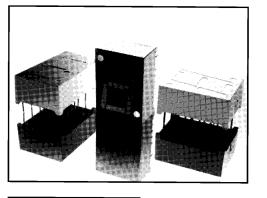


HIGH EFFICIENCY GREEN MAN8400 SERIES



DESCRIPTION

The MAN8400 Series is a family of large digits 0.8-inches in height. This series combines high brightness, large size, good aesthetics and is designed to be used where accurate readable displays need to be viewed over a distance. All models use right hand decimal points. The display ON and OFF contrast has been optimized for high ambient light conditions by use of a neutral Grey face and diffused White segments. Construction makes use of a metal leadframe, plastic reflector cap with epoxyfilled segments and back.

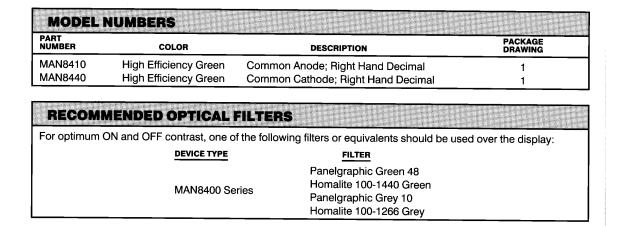
FEATURES

- High Efficiency Green nitrogen-doped GaAsP on GaP
- Large, easy to read, digits
- Common anode or common cathode models
- Fast switching excellent for multiplexing
- Low power consumption
- Bold solid segments that are highly legible
- Solid state reliability long operation life
- Rugged plastic construction
- Directly compatible with integrated circuits
- High brightness with high contrast
- Categorized for Luminous Intensity (See Note 5)
- Wide angle viewing ... 150°
- Low forward voltage
- Two-digit package simplifies alignment and assembly

APPLICATIONS

For industrial and consumer applications such as:

- Digital readout displays
- Instrument panels
- Point of sale equipment
- Digital clocks
- TV and radios



FAIRCHILD

0.800-INCH **SEVEN SEGMENT DISPLAYS**

SEMICONDUCTOR

| | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|--|--|------|------|-------|-------------------------|
| Luminous Intensity, digit average (See Notes 1 and 4) | 750 | 3200 | | μcd | I _F =10 mA |
| Pulsed Luminous Intensity, digit average | 900 | 4000 | | μcd | I₅=60 mA peak 1:6 DF |
| Peak emission wavelength | | 562 | | nm | |
| Dominant wavelength | | 567 | | nm | |
| Spectral line half width | | 30 | | nm | |
| Forward voltage | | 2.2 | 3.0 | V | I _F =20 mA |
| Dynamic resistance (See Figure 1) | | 12 | | Ω | I _F =20 mA |
| Light rise time | | 500 | | nsec | I _F =10 mA |
| Capacitance | | 40 | | pF | V=0, f=MHz |
| Reverse current | 1999 - Contra Co | | 100 | μA | V ₈ =3.0 V |

| ABSOLUTE MAXIMUM RATINGS | |
|---|----------------|
| Power dissipation at 25°C ambient | |
| Derate linearly from 50°C | |
| Storage and operating temperature | −40°C to +85°0 |
| Continuous forward current | |
| Total | |
| Total Per segment Decimal point | |
| Decimal point | |
| Reverse voltage | |
| Per segment | 601 |
| Per segment Decimal point | 0.0 |
| Soldering time at 260°C (See Notes 2 and 3) | |

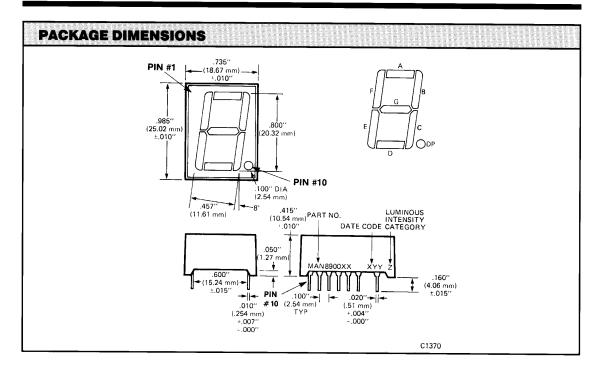
| TYPICAL THERMAL CHARACTERISTICS | |
|---|-----------|
| Thermal resistance junction to free air Φ_{JA} | |
| Wavelength temperature coefficient (case temperature) | 1.0Å/°C |
| Forward voltage temperature coefficient | 1.4 mV/°C |

NOTES

- 1. The digit average Luminous Intensity is obtained by summing the Luminous Intensity of each segment and dividing by the total number of segments. Intensity will not vary more than ±33.3% between all segments within a digit. 2. Leads of the device immersed to 1/16 inch from the body. Maximum device surface temperature is 140°C.
- 3. For flux removal, Freon TF, Freon TE, Isoproponal or water may be used up to their boiling points.
- 4. Intensity adjusted for smaller areas of the "+" and decimal points.
- 5. All displays are categorized for Luminous Intensity. The Intensity category is marked on each part as a suffix letter to the part number.

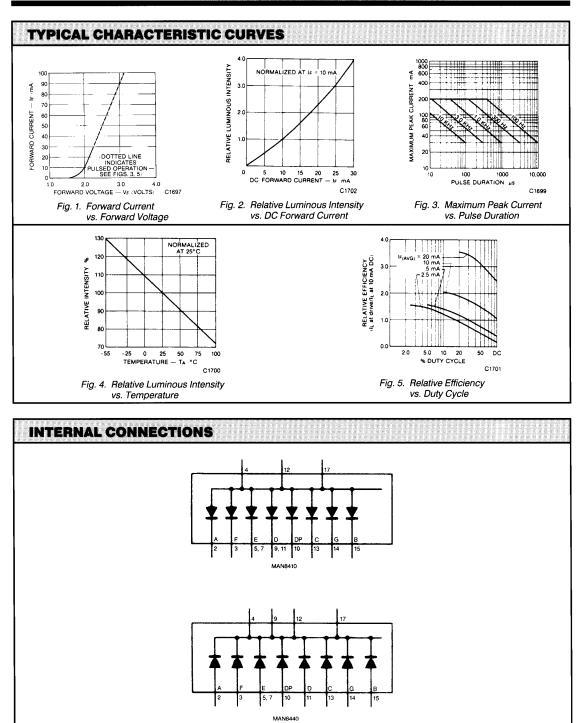


SEMICONDUCTOR



| LECTRICAL CONNECTIONS | | | | | |
|------------------------|--------------------|--------------------|--|--|--|
| ELECTRICAL CONNECTIONS | | | | | |
| | MAN8410 | MAN8440 | | | |
| | Digit | Digit | | | |
| | Common Anode | Common Cathode | | | |
| PIN # | Package Dimensions | Package Dimensions | | | |
| 1 | No Connection | No Connection | | | |
| 2 | A Cathode | A Anode | | | |
| 3 | F Cathode | F Anode | | | |
| 4 | Common Anode | Common Cathode | | | |
| 5 | E Cathode | E Anode | | | |
| 6 | 7 | | | | |
| 7 | E Cathode | E Anode | | | |
| 8 | — | _ | | | |
| 9 | D Cathode | Common Cathode | | | |
| 10 | DP Cathode | DP Anode | | | |
| 11 | D Cathode | D Anode | | | |
| 12 | Common Anode | Common Cathode | | | |
| 13 | C Cathode | C Anode | | | |
| 14 | G Cathode | G Anode | | | |
| 15 | B Cathode | B Anode | | | |
| 16 | _ | - | | | |
| 17 | Common Anode | Common Anode | | | |
| 18 | — | | | | |







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